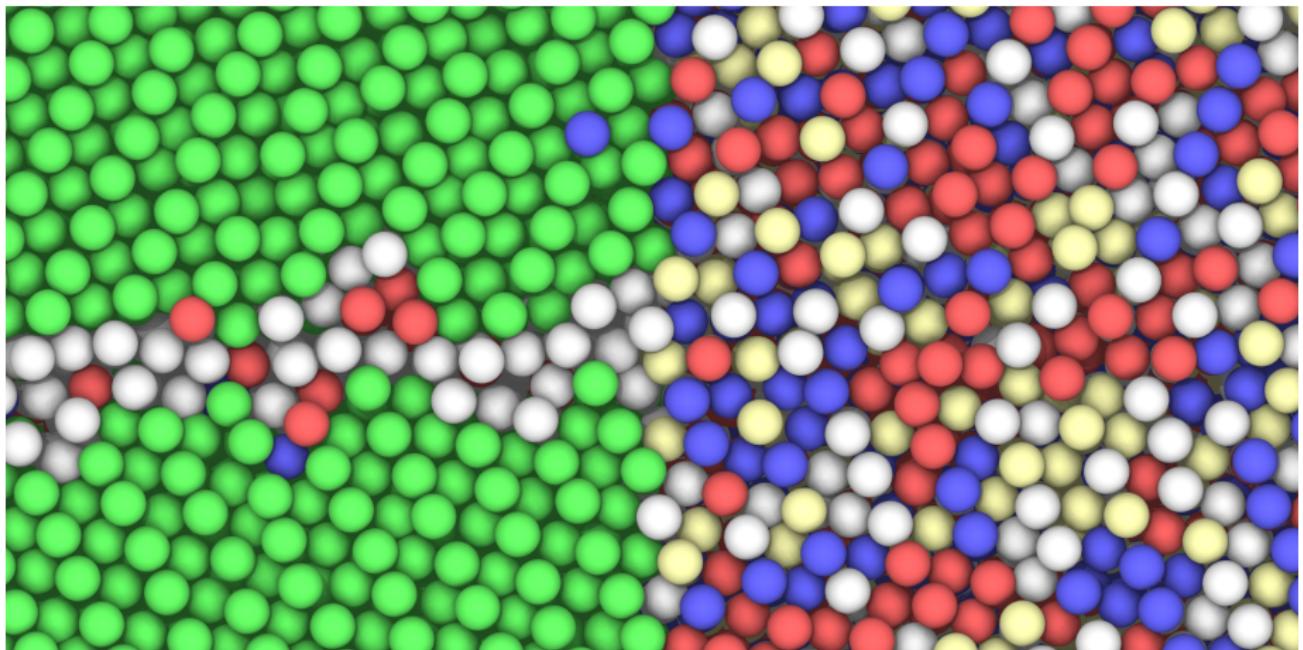


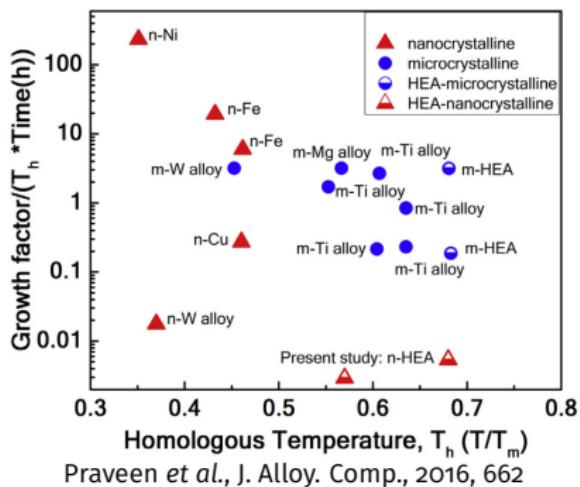
Grain Boundary Effects in High Entropy Alloys: Insights from Atomistic Computer Simulations

D. Utt, A. Stukowski, K. Albe



Motivation

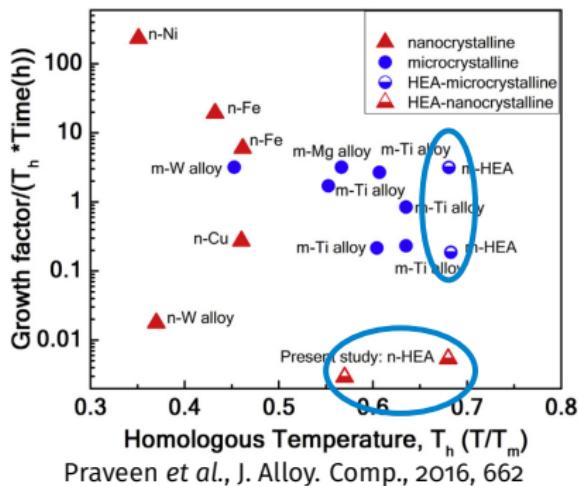
- Growth factor: d_f/d_o



Praveen et al., J. Alloy. Comp., 2016, 662

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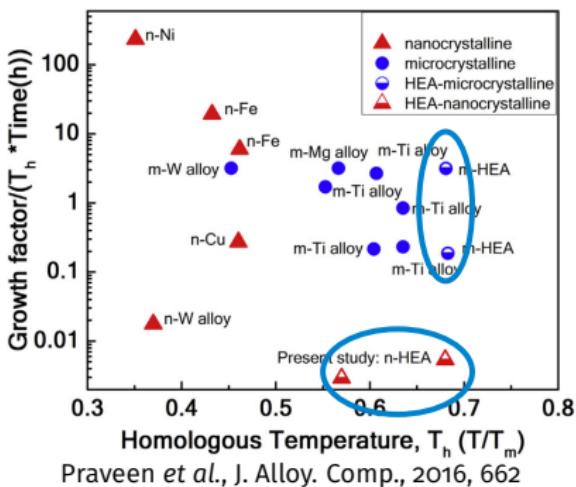
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- ▶ HEA grain growth factor very small



Praveen et al., J. Alloy. Comp., 2016, 662

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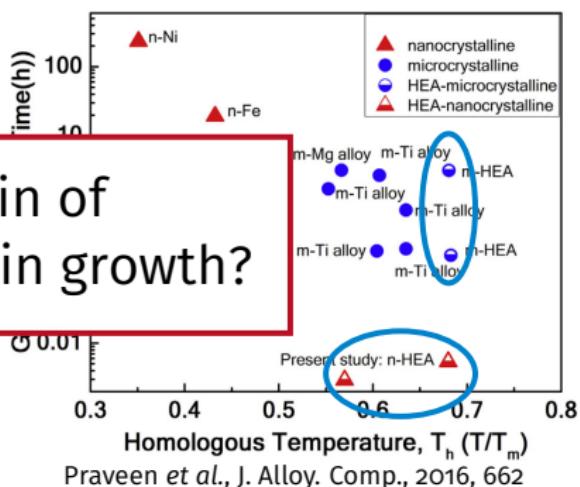


Praveen et al., J. Alloy. Comp., 2016, 662

Motivation

- ▶ Growth factors
- ▶ HEA grain growth small
- ▶ Hall-Petch law

What is the origin of
the reduced grain growth?



Praveen et al., J. Alloy. Comp., 2016, 662

Possible Causes for Reduced Grain Growth

- ▶ Zener pinning on carbides or oxides

Zou *et al.*, Nano Lett., 2017, 17 (3)
Praveen *et al.*, J. Alloy. Comp., 2016, 662

Possible Causes for Reduced Grain Growth

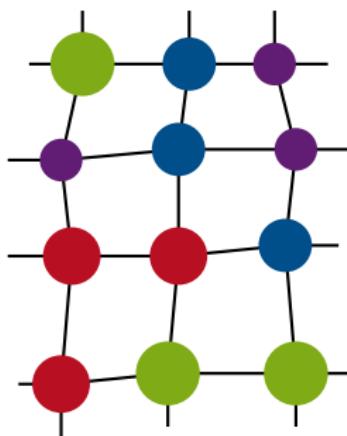
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Possible Causes for Reduced Grain Growth

- ▶ Zener pinning on carbides or oxides
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- ▶ Local lattice distortions



Methodology

- ▶ Atomistic simulations using LAMMPS

www.lammps.sandia.gov

Methodology

- ▶ Atomistic simulations using LAMMPS
- ▶ Equimolar FCC CuNiCoFe HEA
 - ▶ Random configuration (Rand. ...)
 - ▶ Chemical equilibration using hybrid VC-SGC MC/MD

Sadigh *et al.*, Phys. Rev. B, 2012, 85
Koch *et al.*, JAP, 2017, 122

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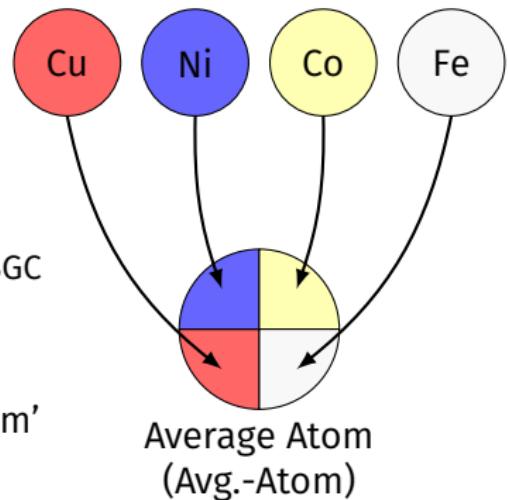
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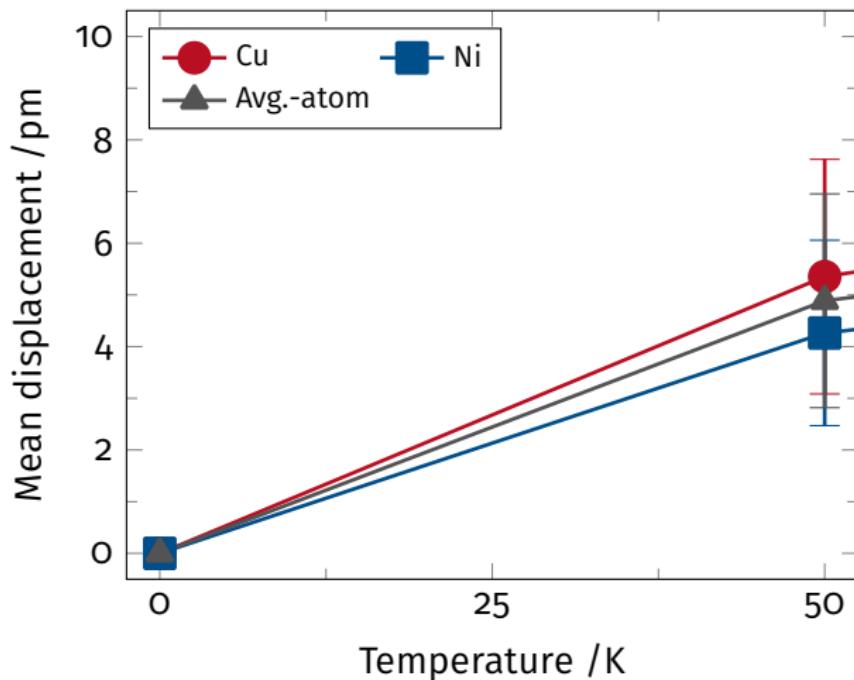
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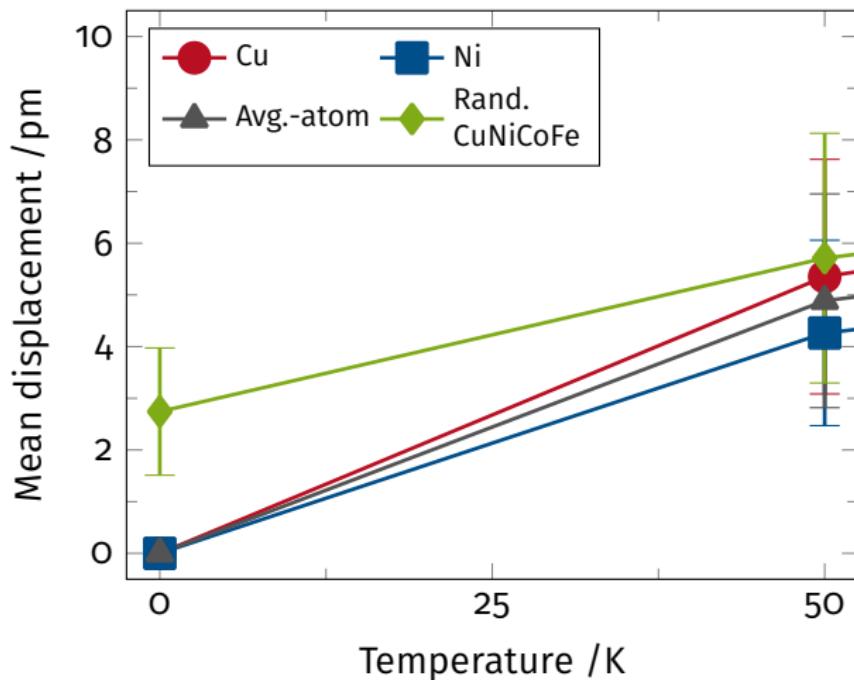
Lattice Distortions

What is the magnitude of the
intrinsic lattice distortions?

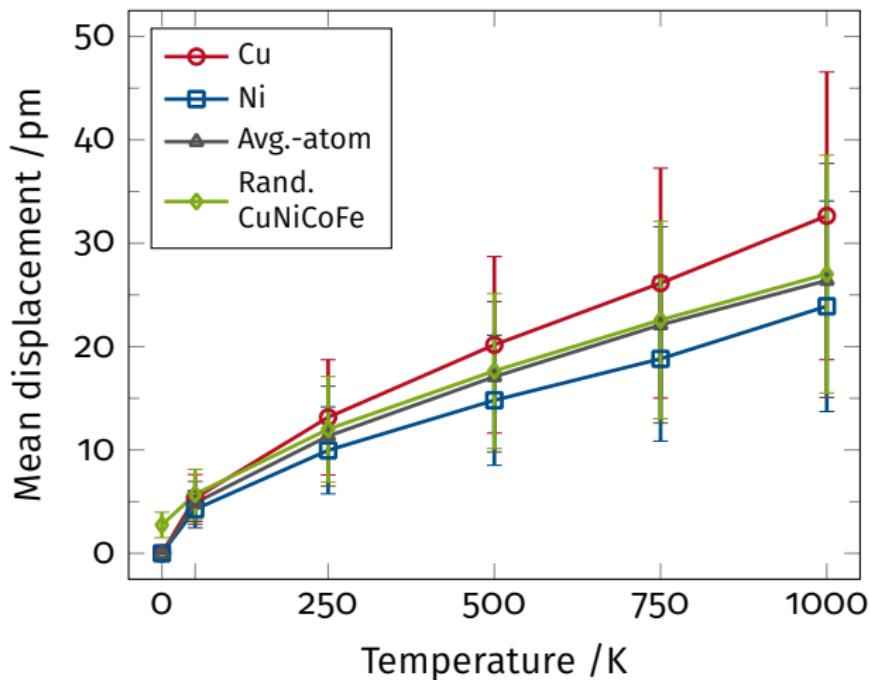
Lattice Distortions



Lattice Distortions



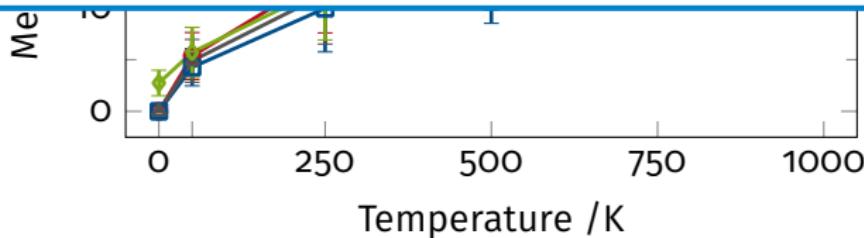
Lattice Distortions



Lattice Distortions



Intrinsic lattice distortions are measurable at 0 K,
but become negligible at higher temperatures.

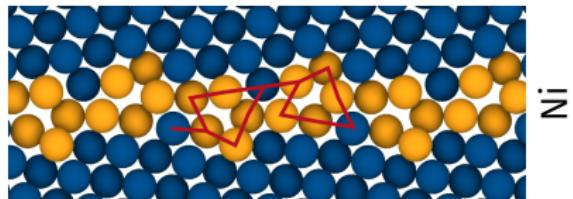
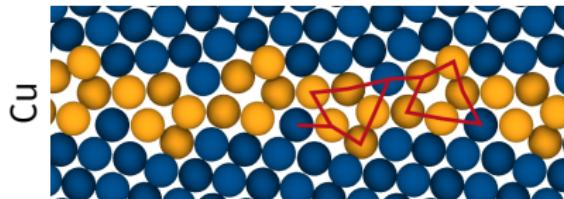


Is there a structural difference for
the GBs in the different materials?

$\Sigma 11(332)\langle 110 \rangle$ STGB o K Structures



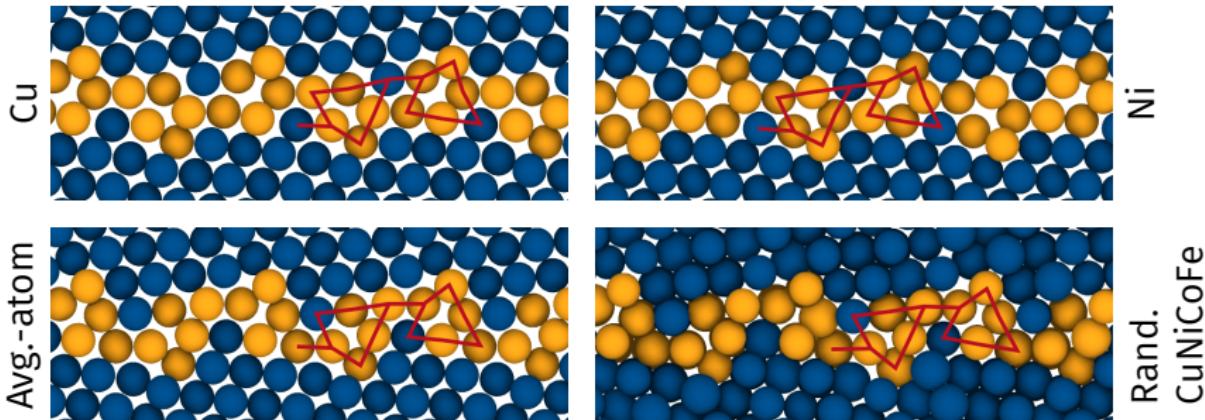
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$\Sigma 11(332)\langle 110 \rangle$ STGB o K Structures



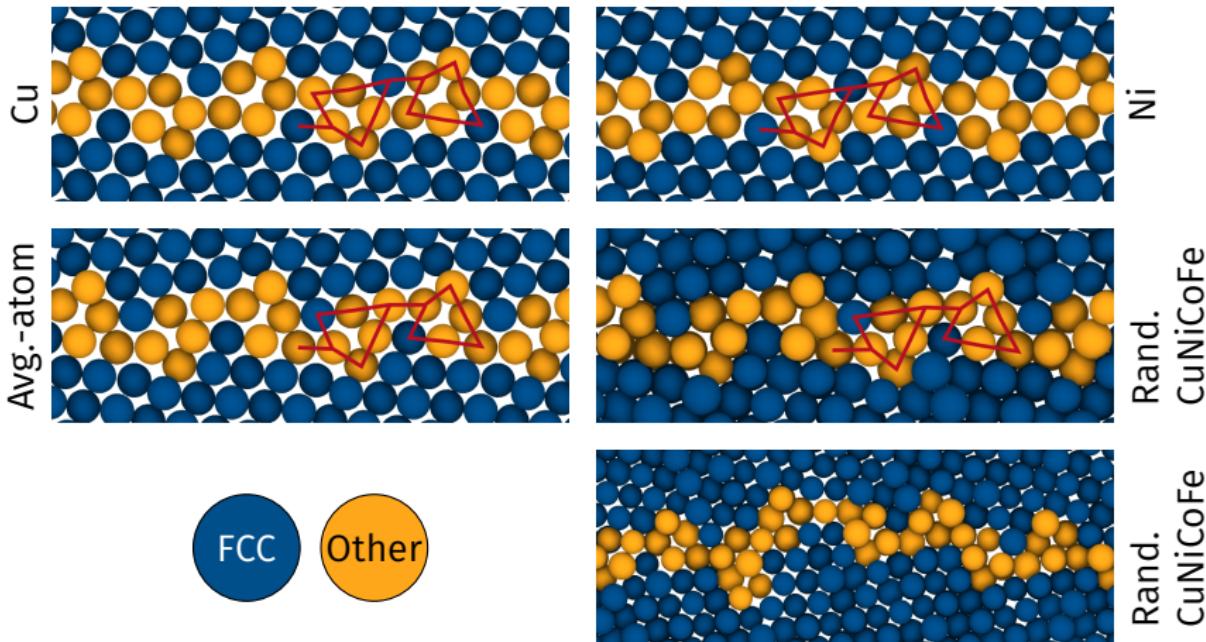
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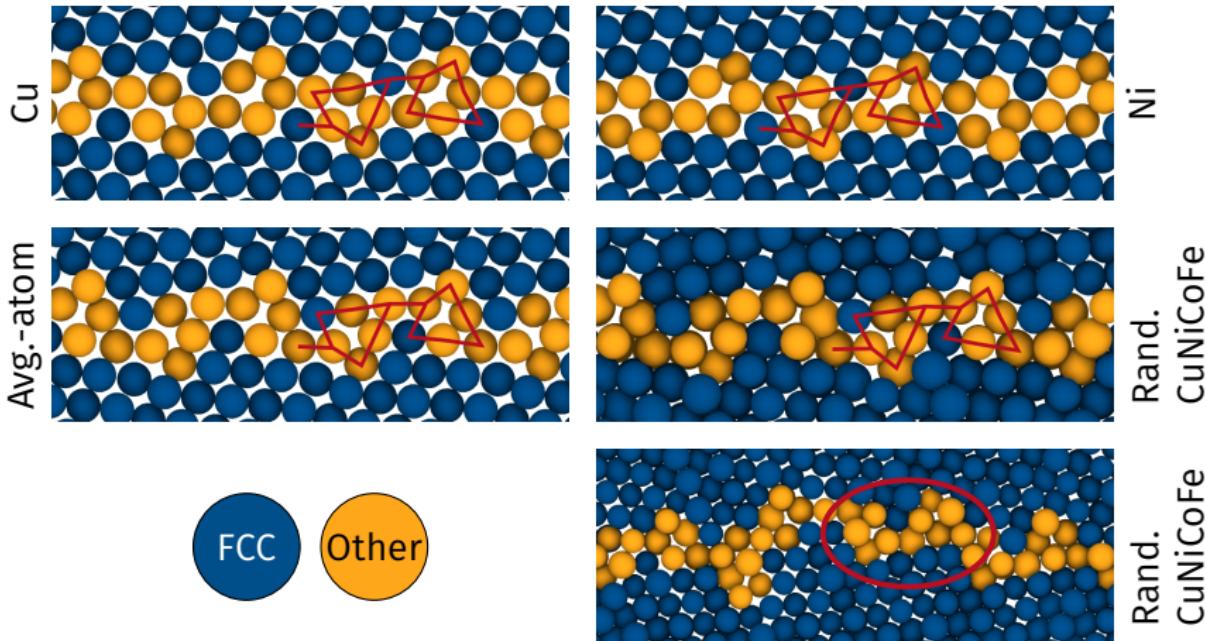
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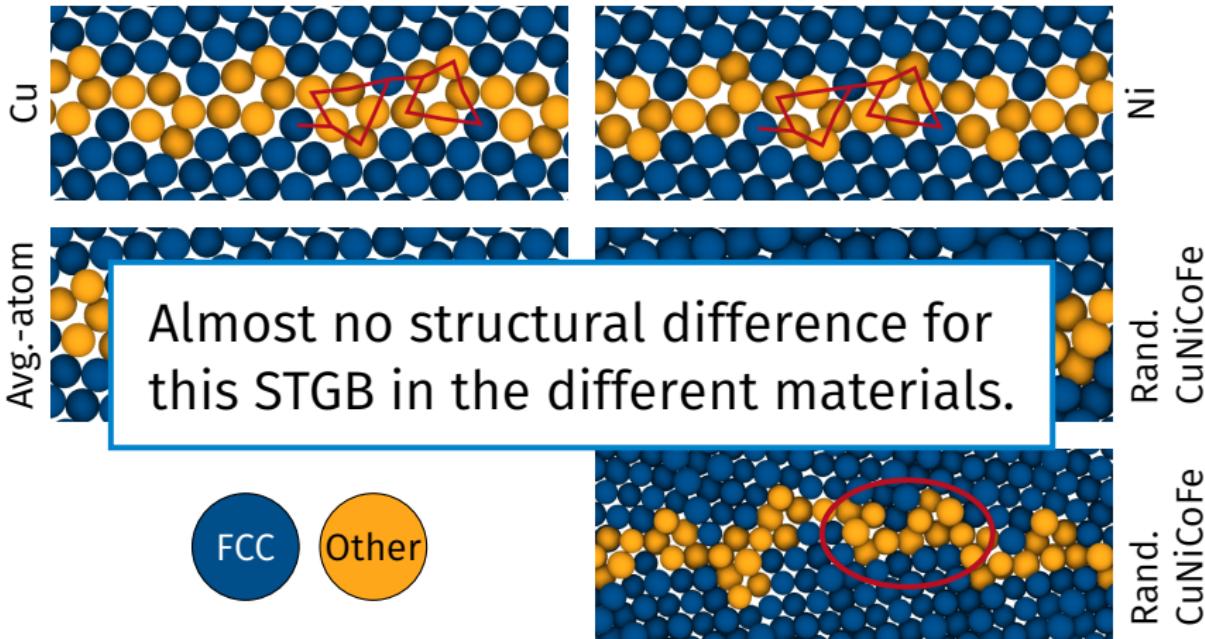
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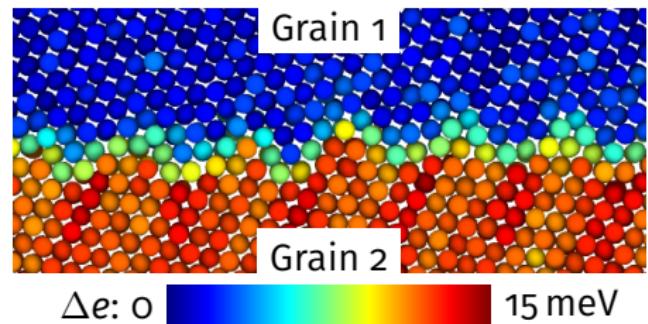
$\Sigma 11(332)\langle 110 \rangle$ STGB o K Structures



Synthetic Driving Force

What are the GB mobilities for the different materials under driven conditions?

Synthetic Driving Force



Janssens et al., Nat. Mater., 2006, 5

Synthetic Driving Force

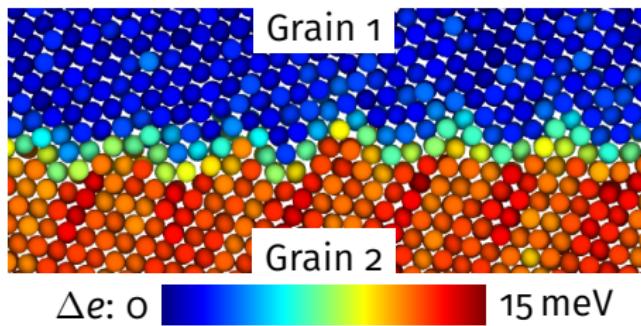
Synthetic driving pressure:

$$P = \frac{\Delta e}{\Omega}$$

GB Mobility:

$$M = \frac{V}{P}$$

$$M(T) = M^\infty \exp \left(\frac{-Q_m}{k_B T} \right)$$



Janssens et al., Nat. Mater., 2006, 5

Synthetic Driving Force

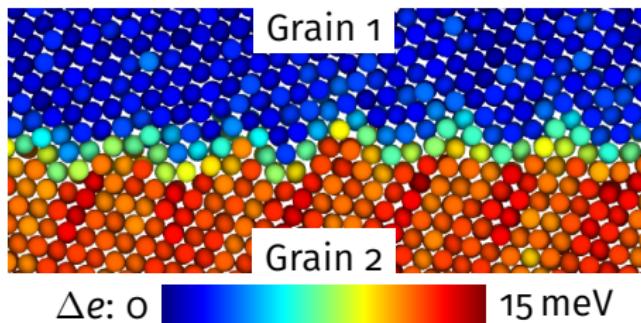
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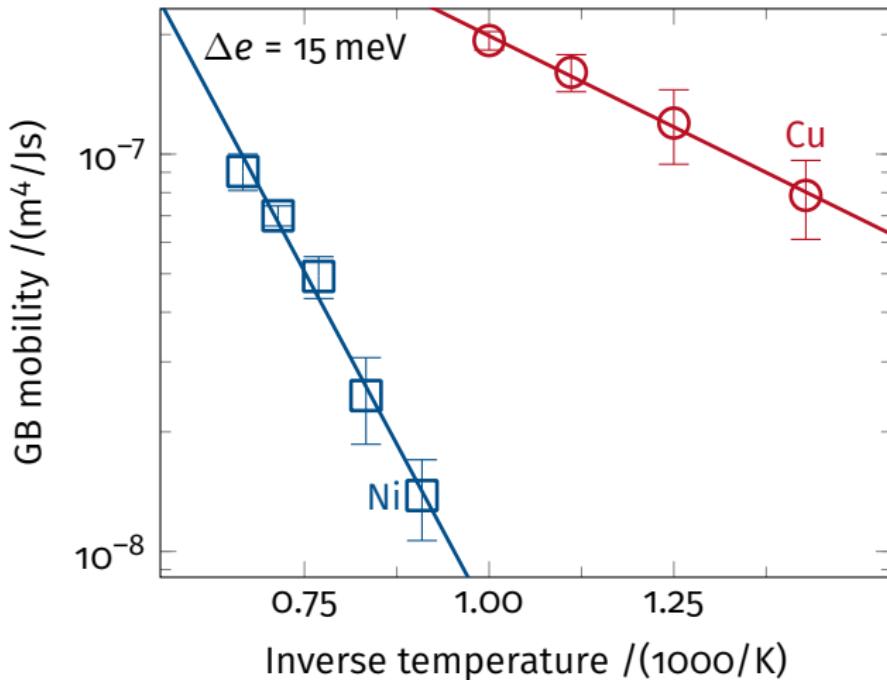
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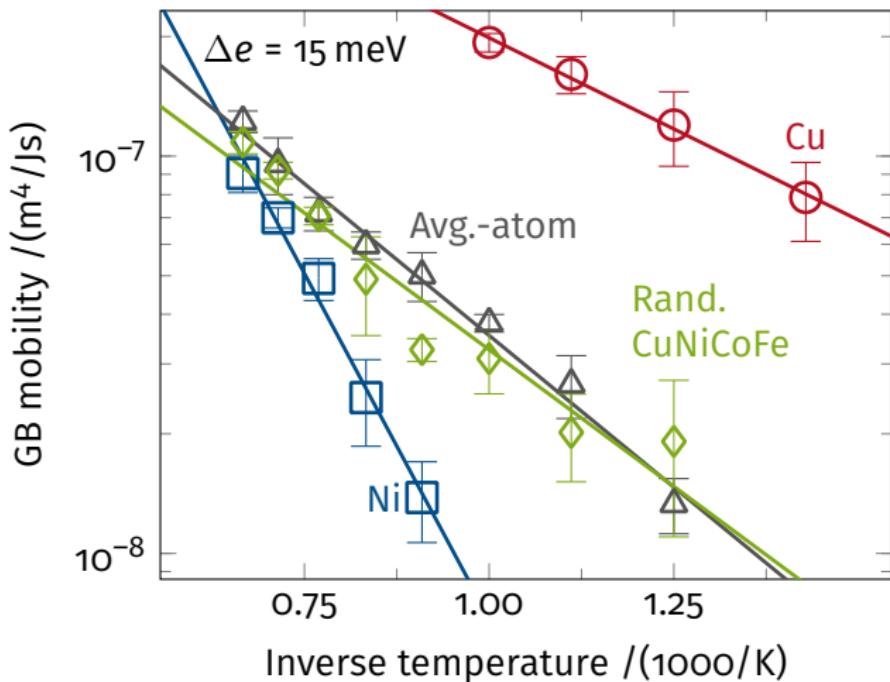
$\Sigma 11(332)\langle 110 \rangle$ STGB Mobility



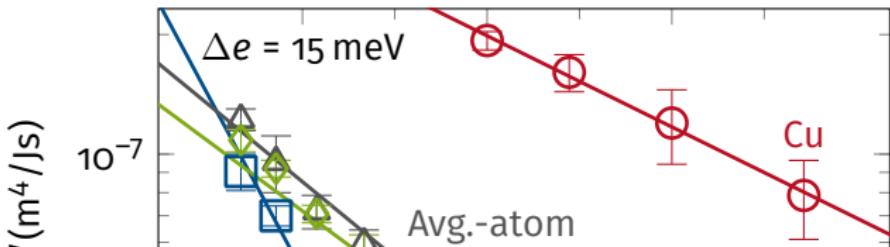
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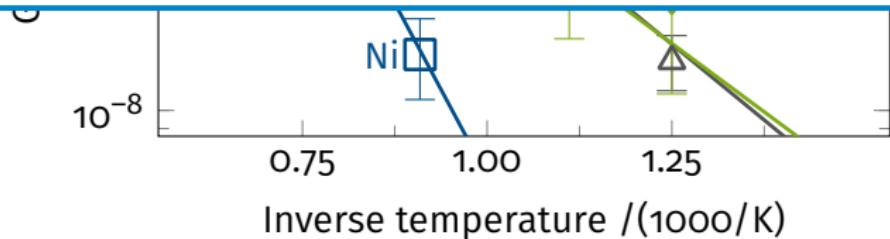
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$\Sigma 11(332)\langle 110 \rangle$ STGB Mobility



Local chemical disorder does not significantly alter the mobility of this STGB.



Σ 11 (332) (110) STGB Segregation & Mobility



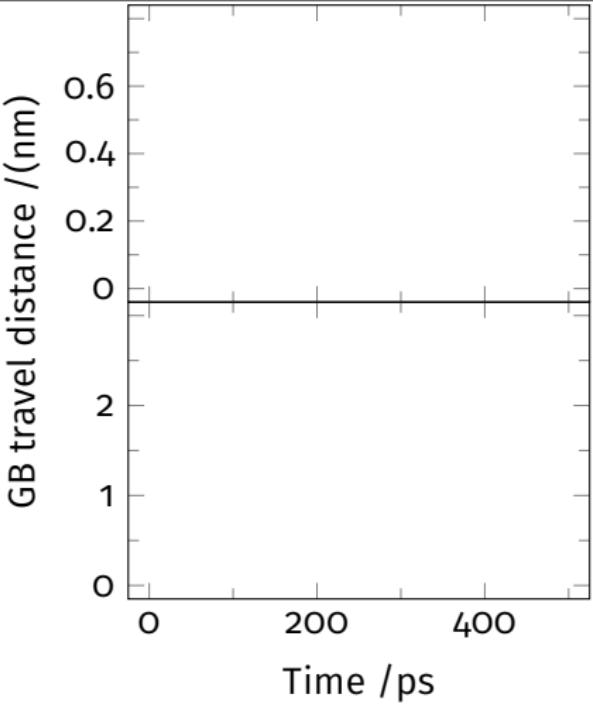
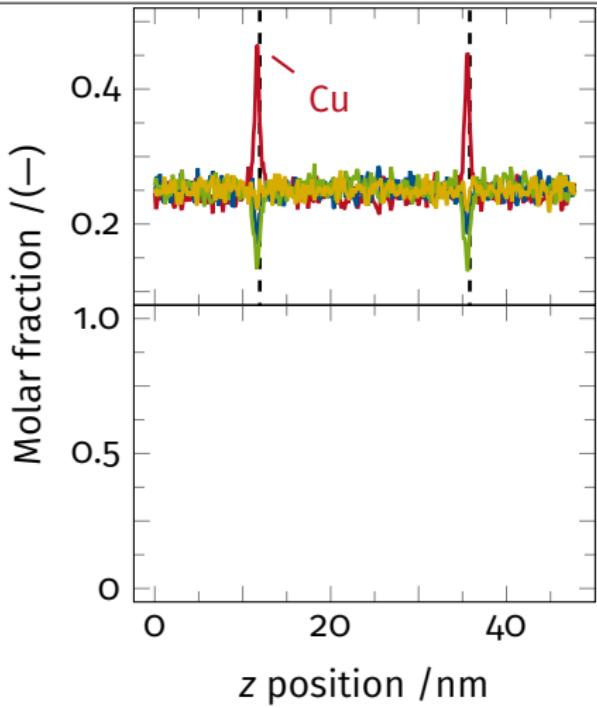
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How is the mobility of this STGB
altered by segregation?

$\Sigma 11$ (332) $\langle 110 \rangle$ STGB Segregation & Mobility



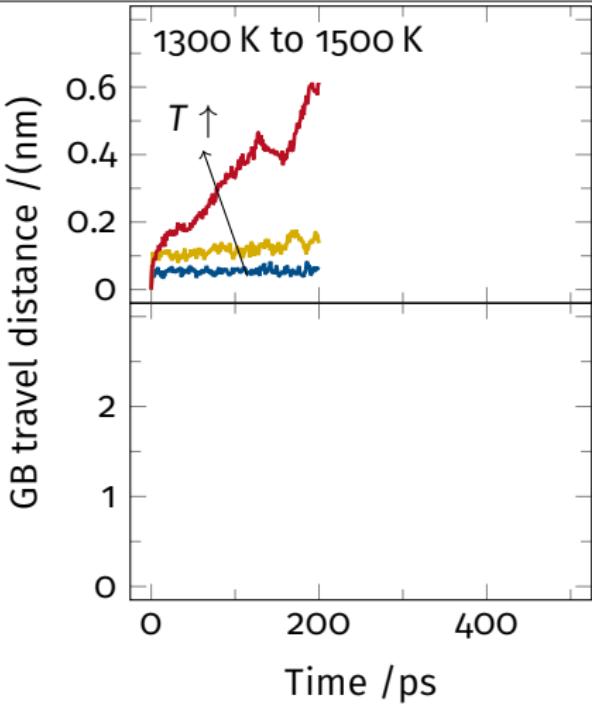
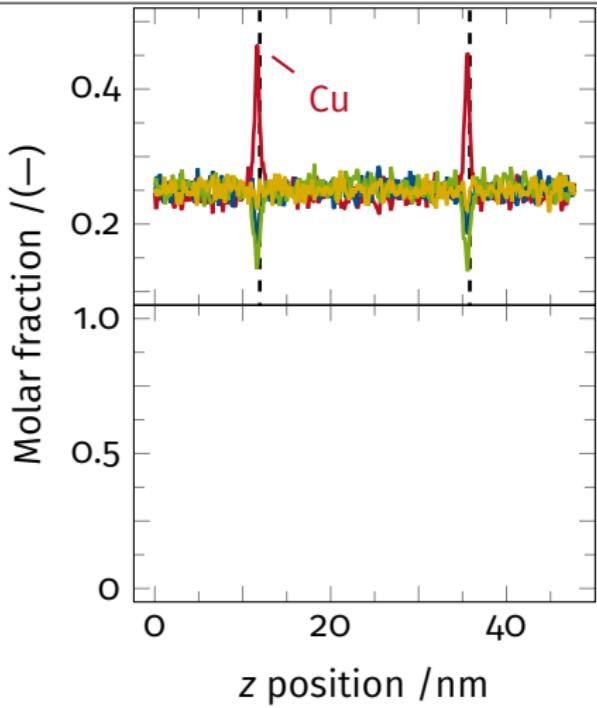
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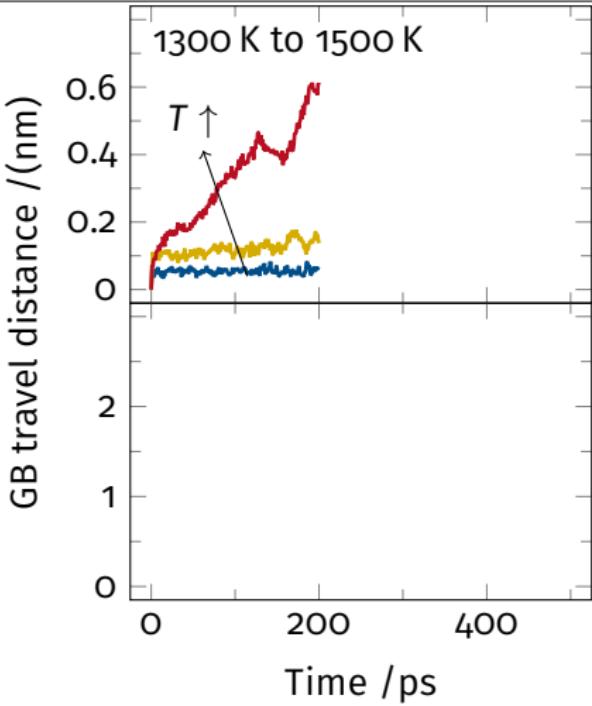
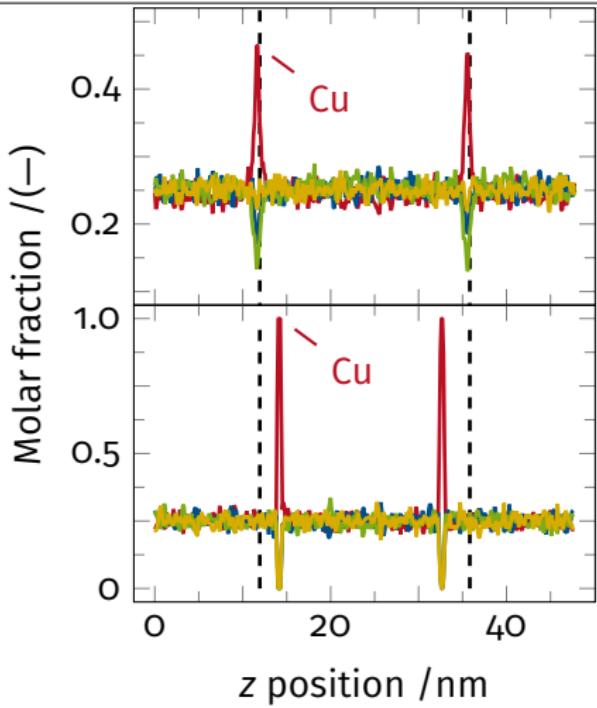
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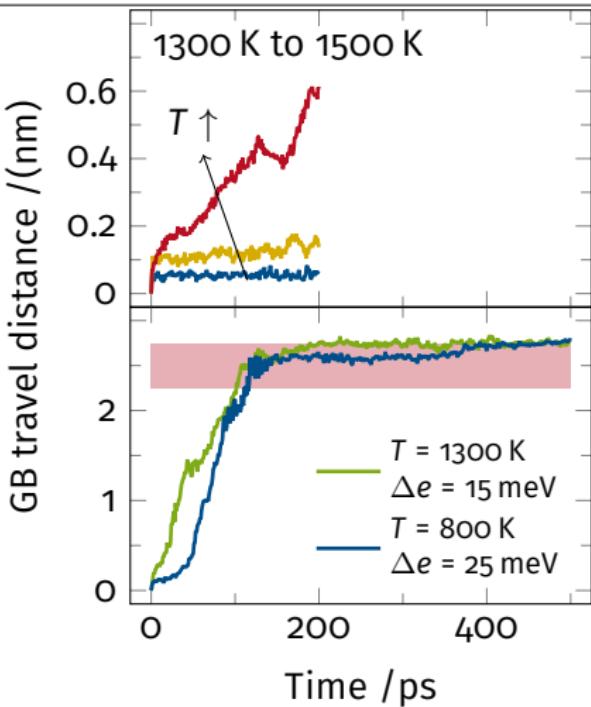
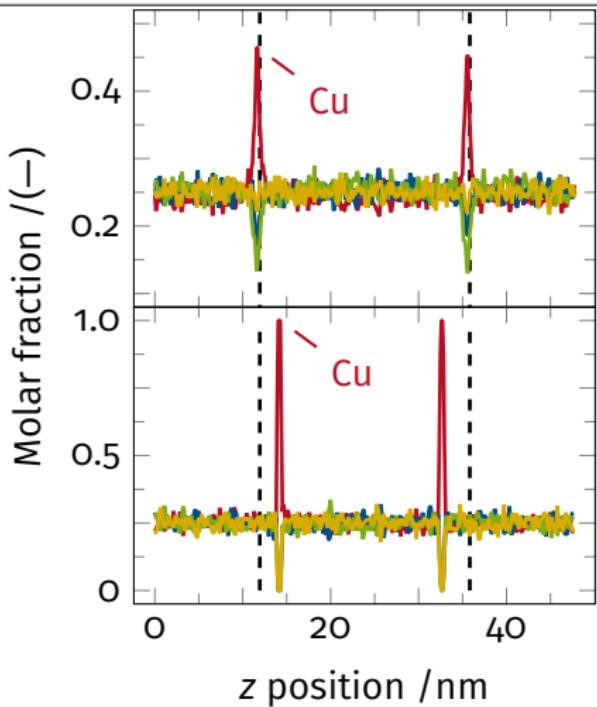
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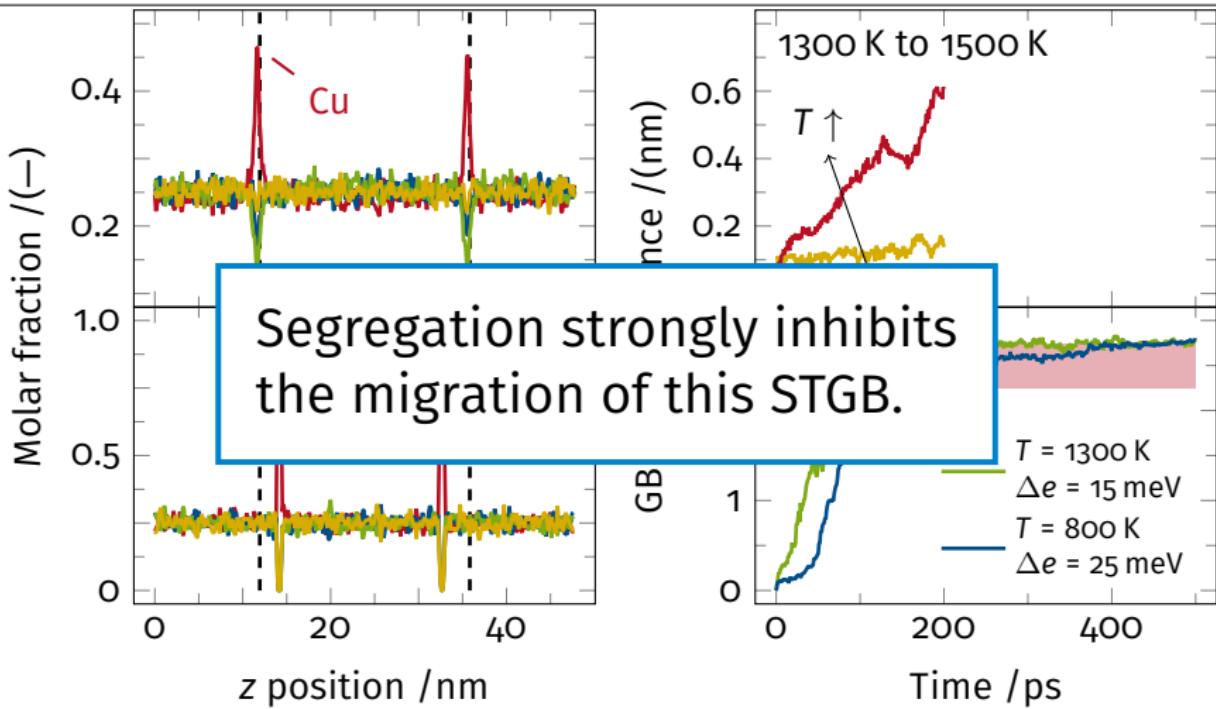
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Nanocrystalline Samples

Expected Grain Growth Rate

How do these findings transfer
to large scale samples containing
general GBs?

Nanocrystalline Samples

Expected Grain Growth Rate

GB velocity:

$$v = M \cdot F$$

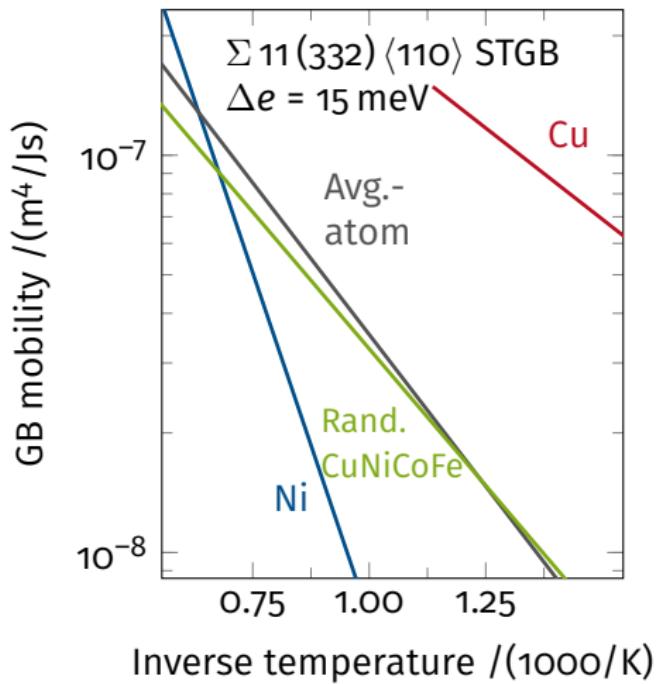
Nanocrystalline Samples Expected Grain Growth Rate



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GB velocity:

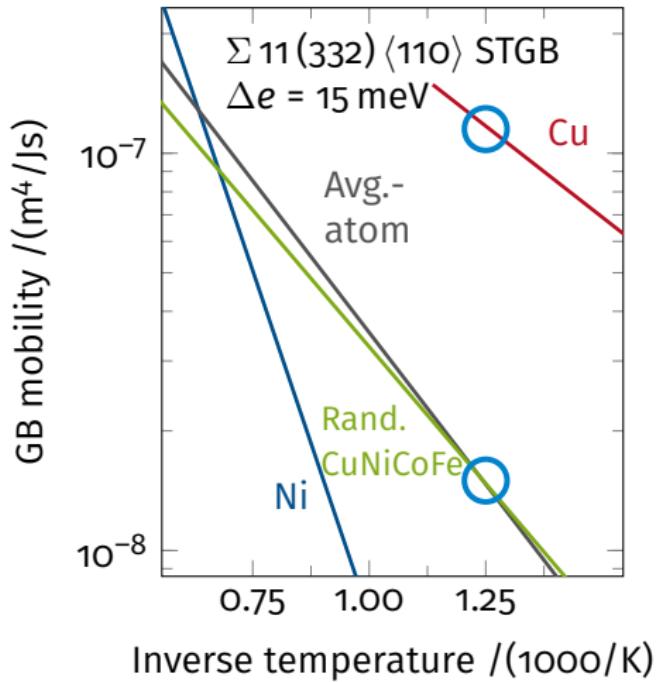
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Nanocrystalline Samples Expected Grain Growth Rate

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Nanocrystalline Samples

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Curvature driven GG:

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Nanocrystalline Samples

Expected Grain Growth Rate



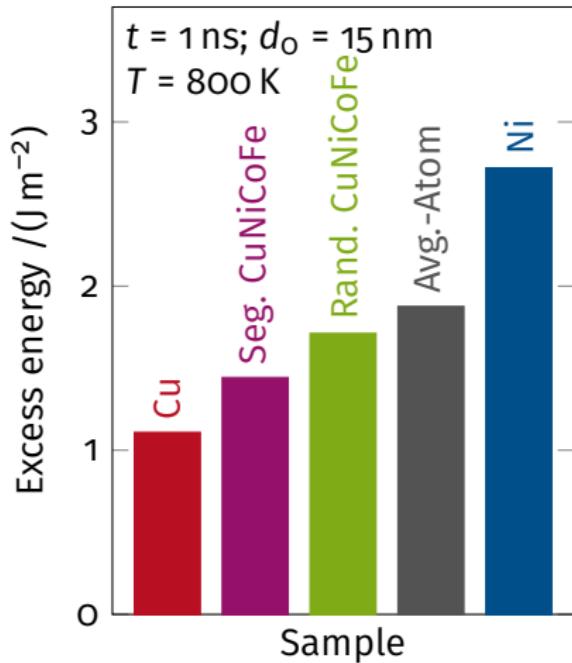
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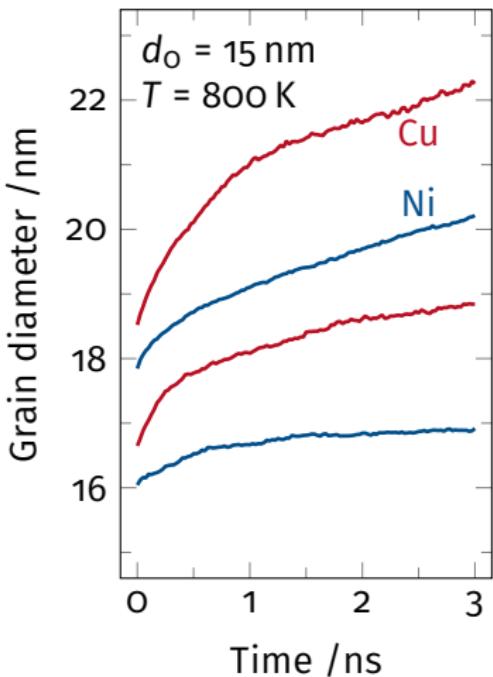
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Nanocrystalline Samples

Grain Diameter Evolution

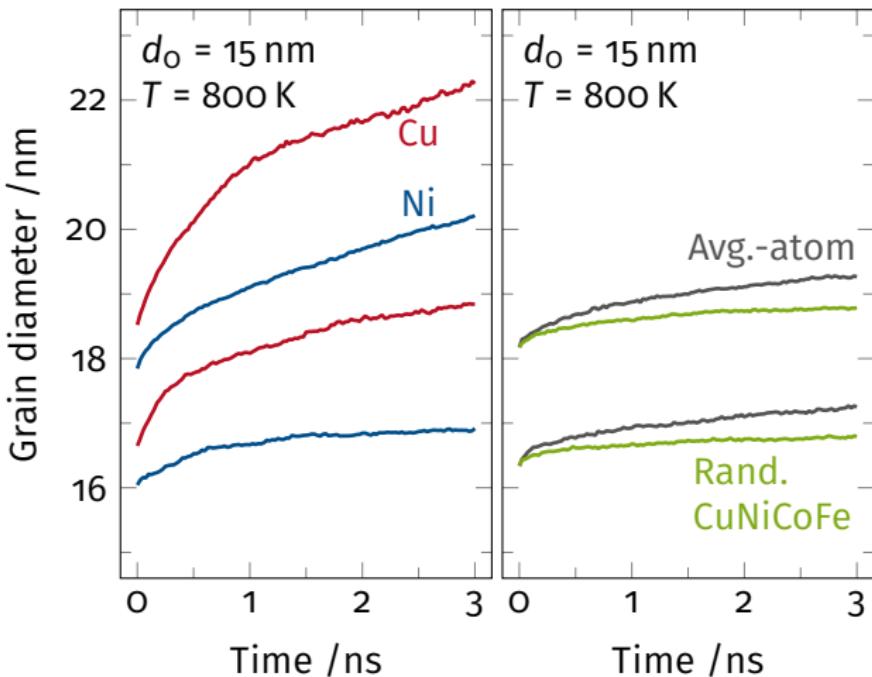


Nanocrystalline Samples

Grain Diameter Evolution



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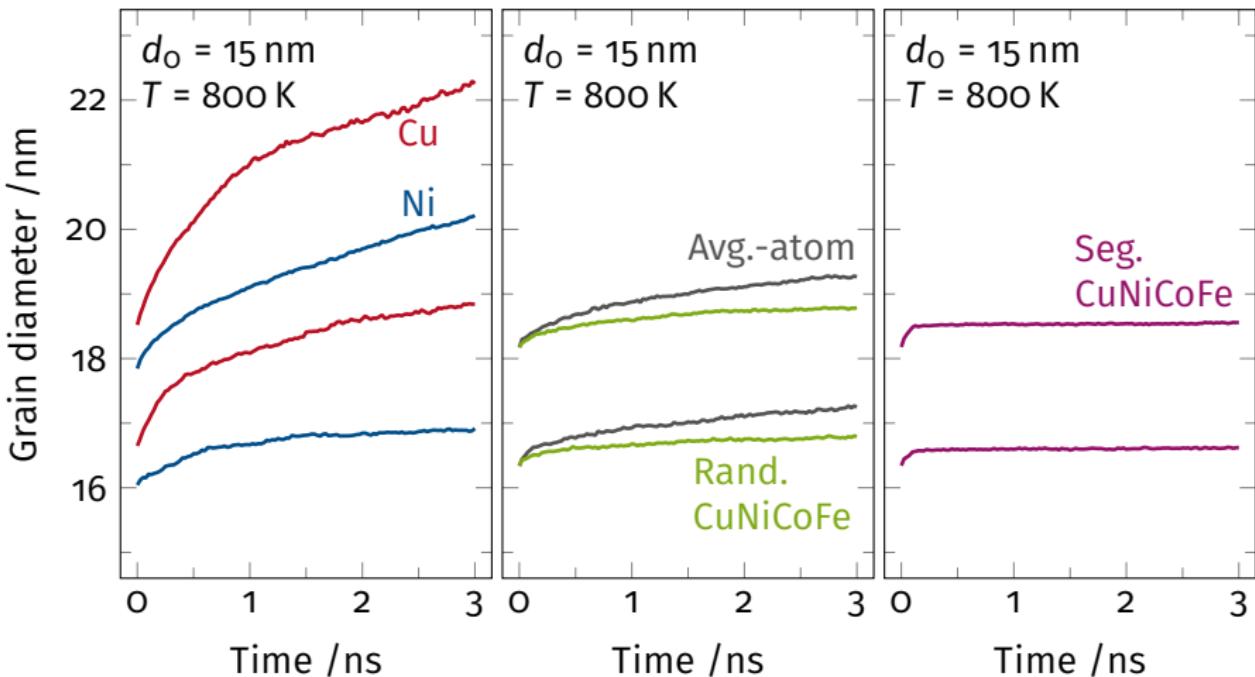


Nanocrystalline Samples

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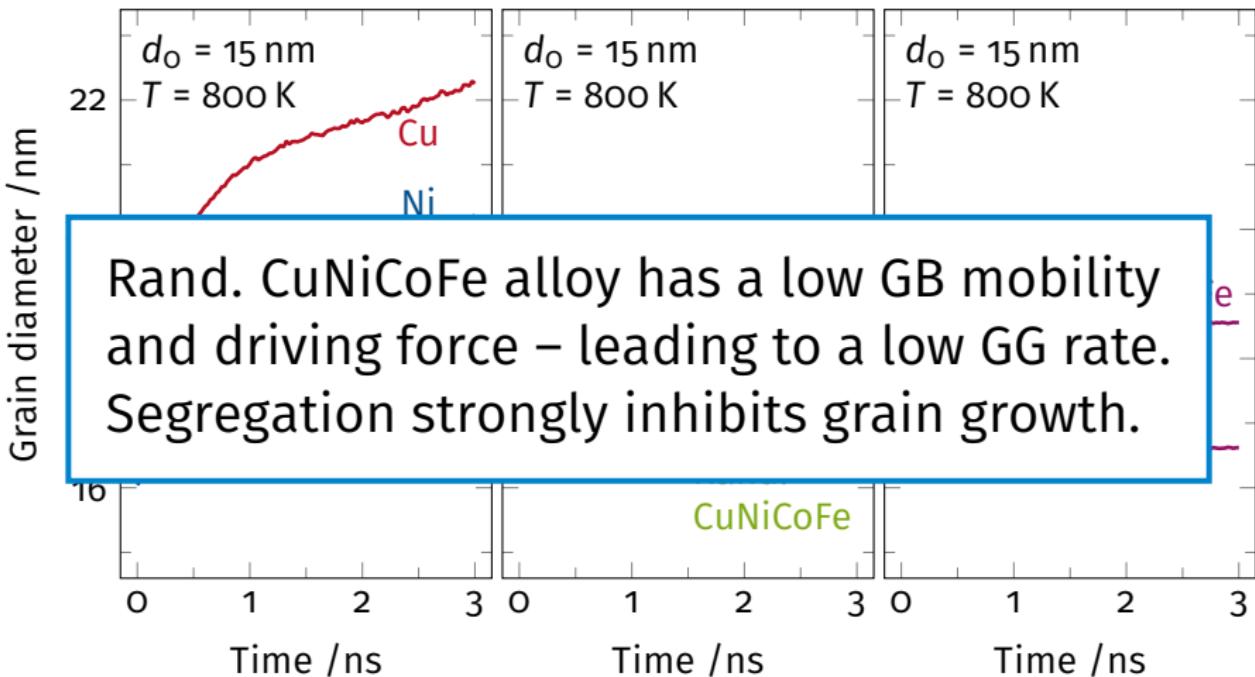


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Nanocrystalline Samples

Grain Diameter Evolution



Summary

- ▶ Lattice distortions in the CuNiCoFe HEA are influential at 0 K, but become negligible above 50 K.

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Summary

- ▶ Lattice distortions in the CuNiCoFe HEA are influential at 0 K, but become negligible above 50 K.
- ▶ Monoatomic samples show a perfect GB structure, localized deviations in the HEA.
- ▶ Avg.-atom and random HEA show almost identical GB mobilities, indicating that the local chemical fluctuations do not hinder GB migration.
- ▶ Segregation strongly inhibits grain growth.



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'Compositionally Complex Alloys –
High Entropy Alloys'

SPP 2006; STU 611/2-1



Properties of the avg.-atom

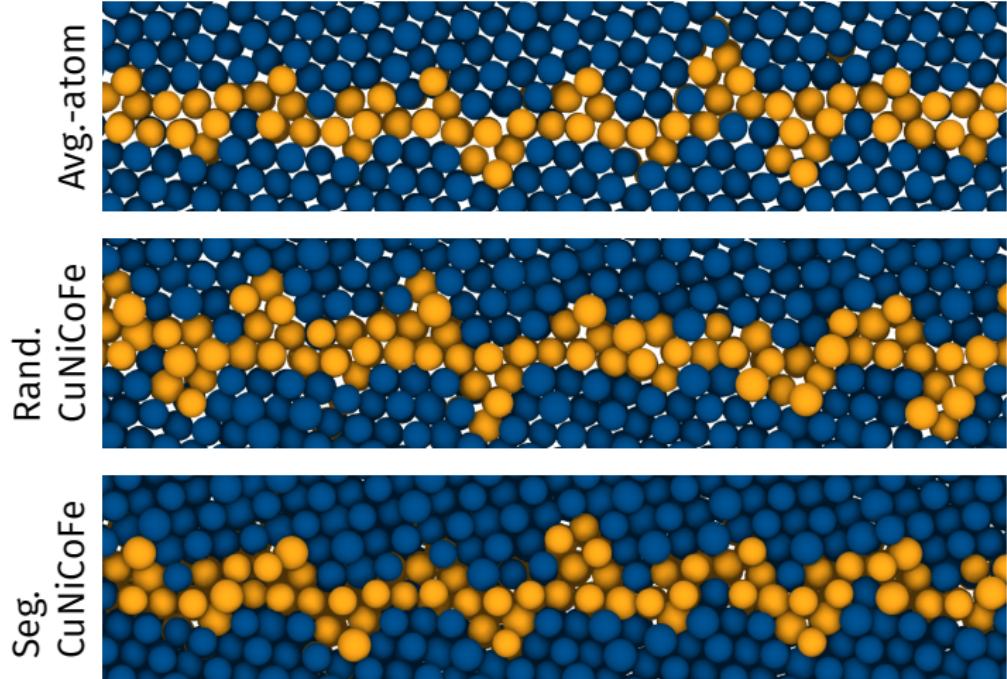


		Rand. CuNiCoFe	Avg. Atom
a_0	(Å)	3.57	3.57
E_{Coh}	(eV)	-4.14	-4.14
C_{11}	(GPa)	172	170
C_{12}	(GPa)	124	120
C_{44}	(GPa)	101	100
α	($\times 10^{-6} \text{ K}^{-1}$)	21	21
T_{Melt}	(K)	1550	1425
γ_{SF}	(mJ m $^{-2}$)	28.5	27.0
γ_{USF}	(J m $^{-2}$)	126.9	129.7

$\Sigma 11 (332) \langle 110 \rangle$ STGB 400 K GB Structures



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$\Sigma 11(332)\langle 110 \rangle$ STGB Position

